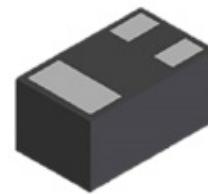


## Description

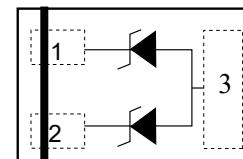
The PESDUC3FD3V3U ESD protector is designed to replace multilayer varistors(MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PESDUC3FD3V3U protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PESDUC3FD3V3U is available in a DFN1006-3L package with working voltages of 3.3 volt. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium.



**DFN1006-3L (Bottom View)**

## Feature

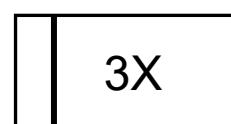
- Ultra low capacitance 0.5pF
- DFN1006-3L package
- Replacement for MLV (0402)
- Unidirectional configurations
- Response time is typically < 1 ns
- Protect one I/O or power line
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to  
IEC 61000-4-2(ESD)±15kV (air), ±12kV (contact);



**Circuit Diagram**

## Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players



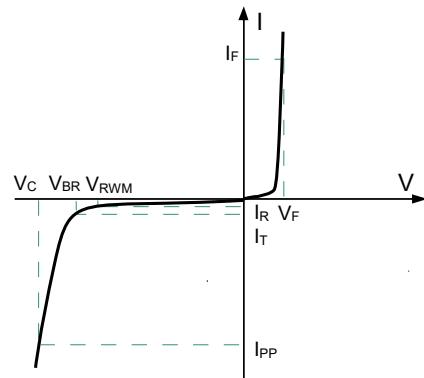
**Marking (Top View)**

## Mechanical Characteristics

- DFN1006-3L without plating
- Mounting position: Any
- Qualified max reflow temperature: 260°C
- Device meets MSL 1 requirements

## Electronics Parameter

Symbol	Parameter
$V_{RWM}$	Peak Reverse Working Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$P_{PP}$	Peak Pulse Power
$C_J$	Junction Capacitance
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



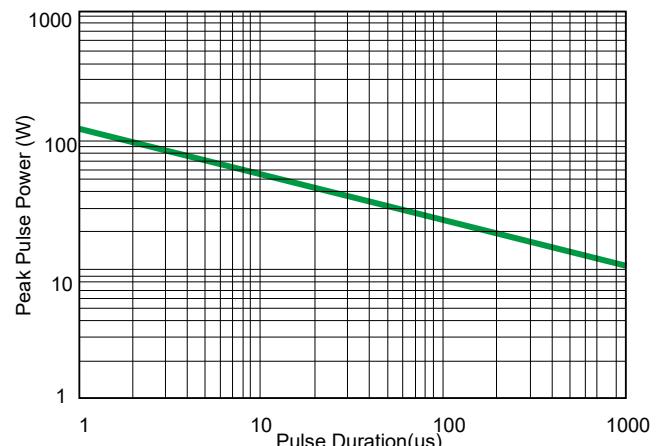
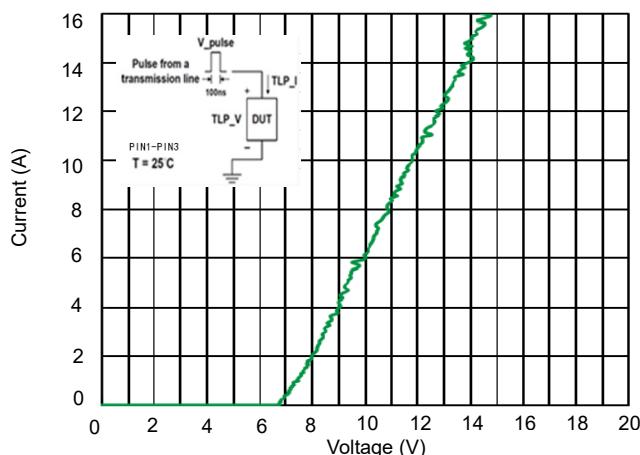
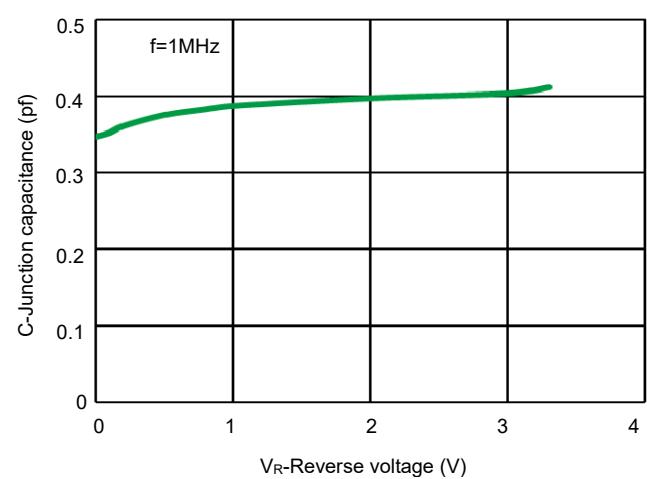
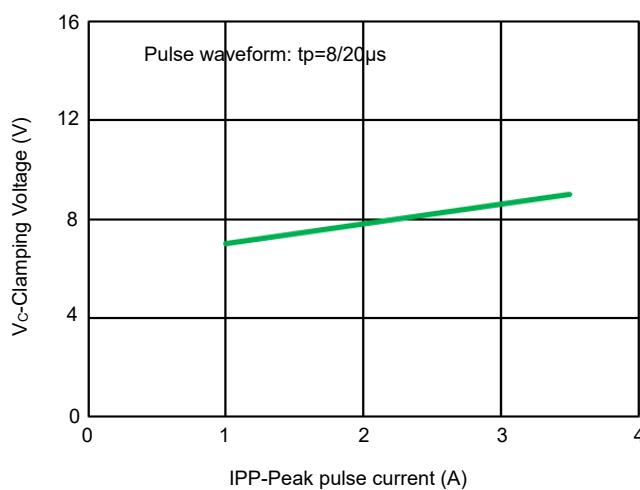
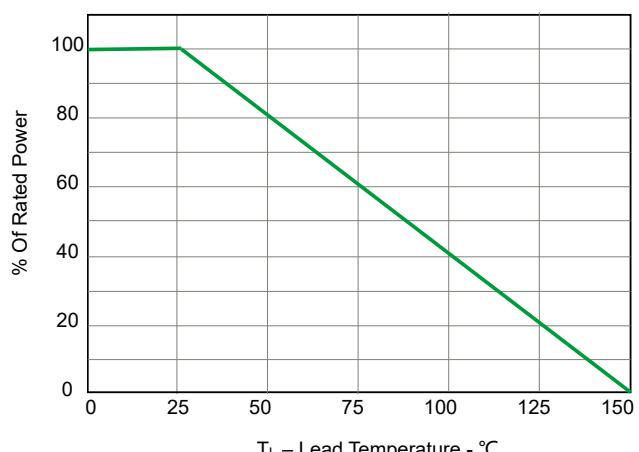
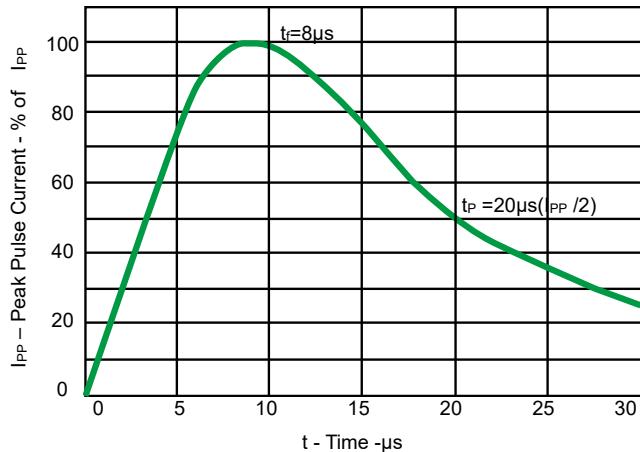
## Electrical characteristics per line@25°C( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Working Voltage	$V_{RWM}$				3.3	V
Breakdown Voltage	$V_{BR}$	$I_t = 1\text{mA}$	4.5			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3\text{V}$			1.0	$\mu\text{A}$
Forward Voltage	$V_F$	$I_F = 10\text{mA}$		0.8	1.2	V
Clamping Voltage	$V_C$	$I_{PP}=1\text{A}$ $t_P = 8/20\mu\text{s}$		7.0	8.0	V
Clamping Voltage	$V_C$	$I_{PP}=3.5\text{A}$ $t_P = 8/20\mu\text{s}$		9.0	11.0	V
Junction Capacitance	$C_J$	$V_R=0\text{V}$ $f = 1\text{MHz}$		0.42	0.50	pF

## Absolute maximum rating@25°C

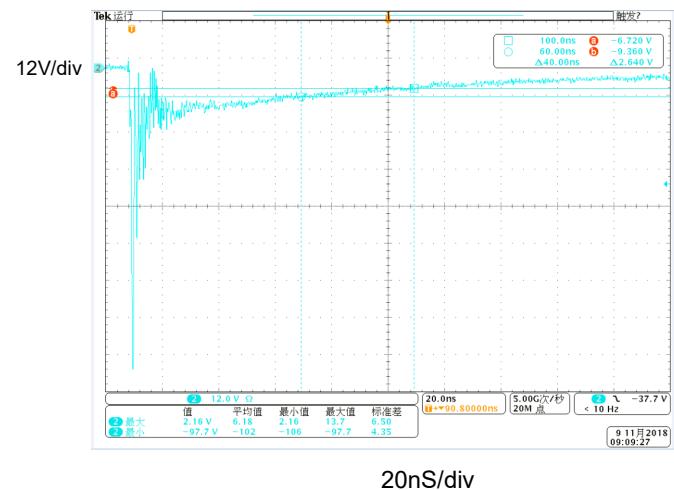
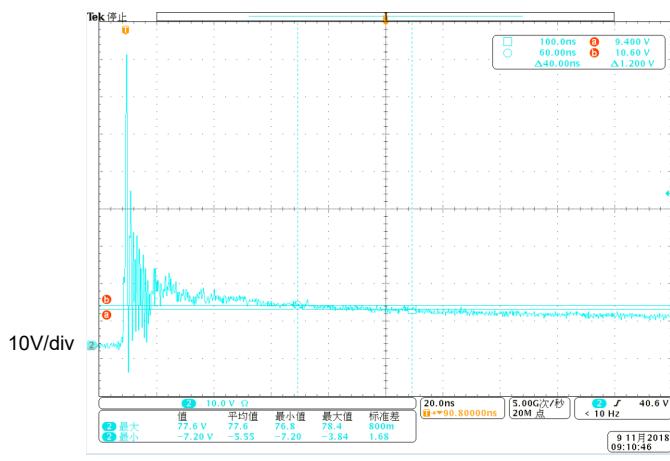
Rating	Symbol	Value	Unit
Peak Pulse Power ( $t_p=8/20\mu\text{s}$ )	$P_{pp}$	40	W
Lead Soldering Temperature	$T_L$	260(10 sec)	°C
Operating Temperature	$T_J$	-55 to 125	°C
Storage Temperature	$T_{STG}$	-55 to 150	°C

## Typical Characteristics

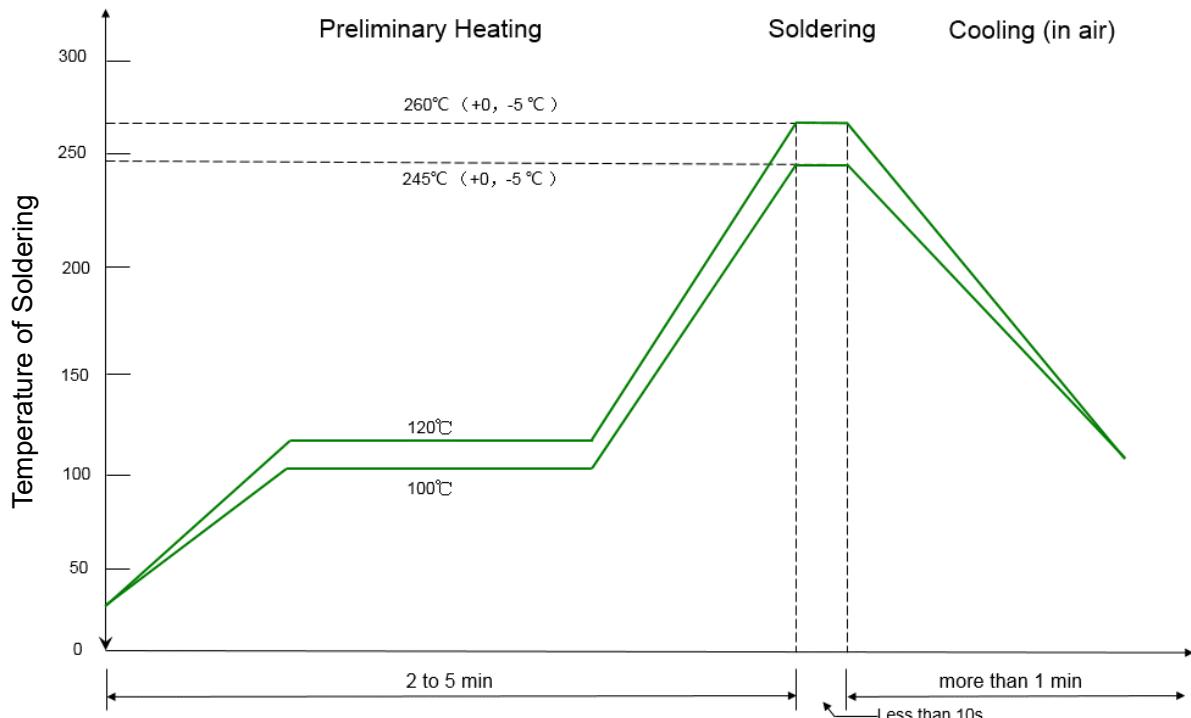


## Ultra Small ESD Protector

PESDUC3FD3V3U



## Solder Reflow Recommendation



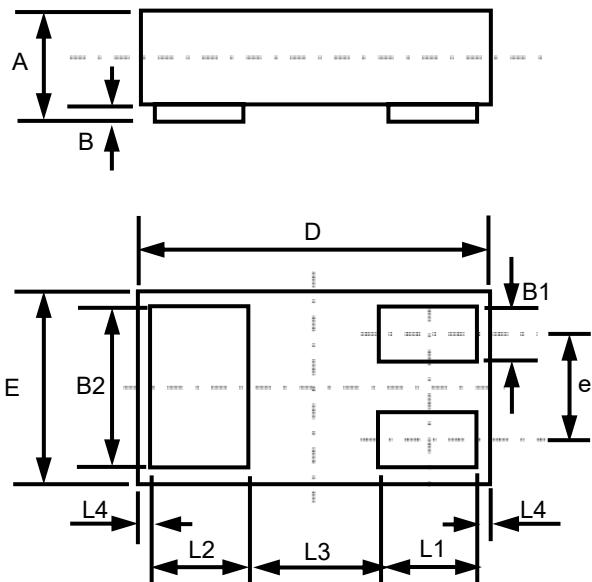
Remark: Pb free for 260°C; Pb for 245°C.

## PCB Design

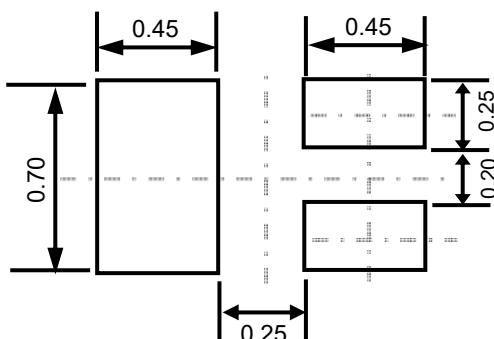
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

## Product dimension (DFN1006-3L)



Dim	Millimeters		
	MIN	Typ	MAX
A	0.33	0.47	0.498
B	0.00	0.03	0.05
B1	0.10	0.15	0.20
B2	0.45	0.50	0.55
D	0.85	1.00	1.15
E	0.45	0.60	0.75
e	--	0.35	--
L1	0.20	0.25	0.30
L2	0.20	0.25	0.30
L3	--	0.39	--
L4	--	0.05	--



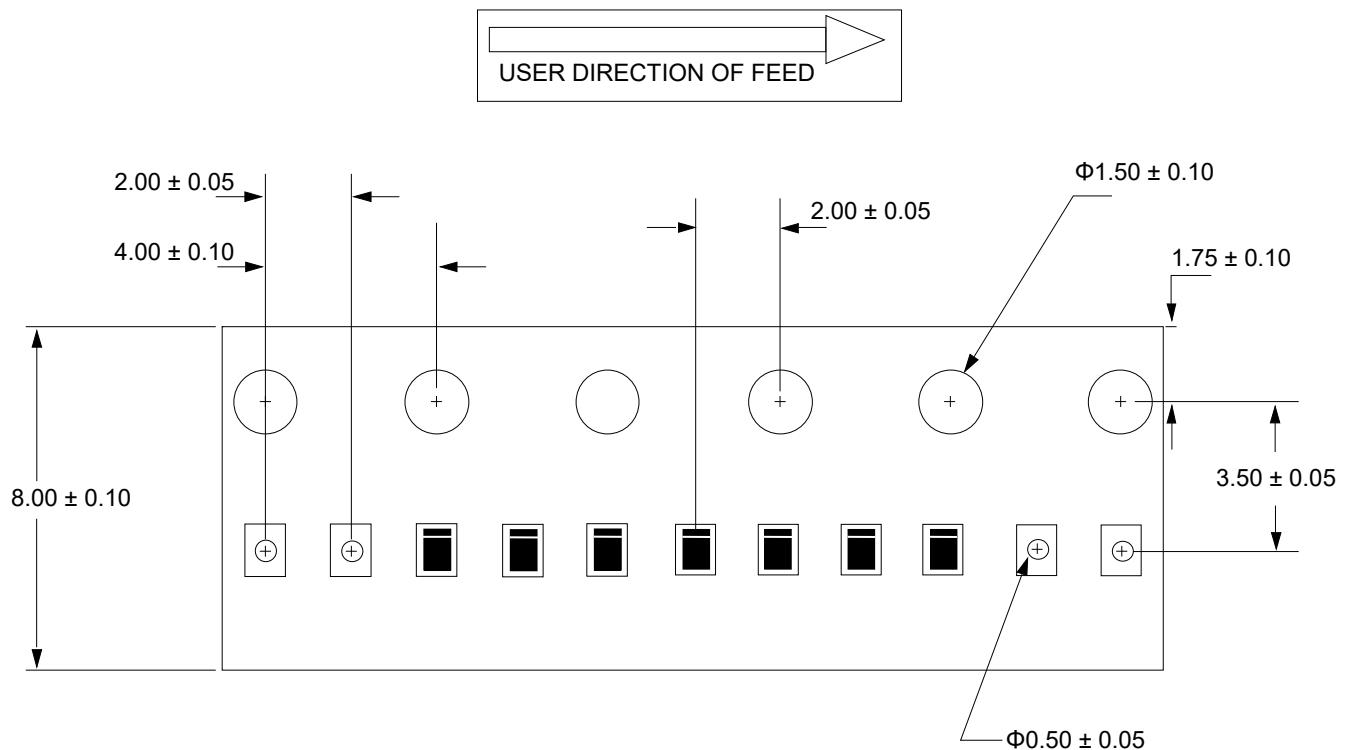
Unit:mm

Suggested PCB Layout

## Ordering information

Device	Package	Reel	MPQ
PESDUC3FD3V3U	DFN1006-3L (Pb-Free)	7"	10000 / Tape & Reel

## Load with information



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